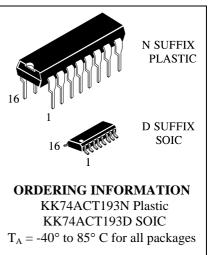
KK74ACT193

Presettable 4-Bit Binary UP/DOWN Counter High-Speed Silicon-Gate CMOS

The KK74ACT193 is identical in pinout to the LS/ALS192, HC/HCT192. The KK74ACT193 may be used as a level converter for interfacing TTL or NMOS outputs to High Speed CMOS inputs.

The counter has two separate clock inputs, a Count Up Clock and Count Down Clock inputs. The direction of counting is determined by which input is clocked. The outputs change state synchronous with the LOW-to-HIGH transitions on the clock inputs. This counter may be preset by entering the desired data on the P0, P1, P2, P3 input. When the Parallel Load input is taken low the data is loaded independently of either clock input. This feature allows the counters to be used as devide-by-n by modifying the count lenght with the preset inputs. In addition the counter can also be cleared. This is accomplished by inputting a high on the Master Reset input. All 4 internal stages are set to low independently of either clock input.Both a Terminal Count Down (TC_D) and Terminal Count Up (TC_U) Outputs are provided to enable cascading of both up and down counting functions. The TC_D output produces a negative going pulse when the counter underflows and TC_{II} outputs a pulse when the counter overflows. The counter can be cascaded by connecting the TC_{U} and TC_D outputs of one device to the Count Up Clock and Count Down Clock inputs, respectively, of the next device.

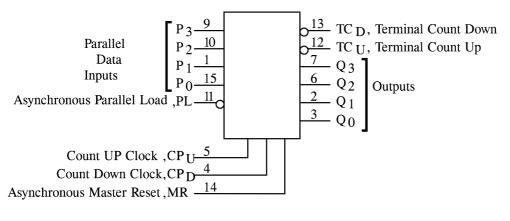
- TTL/NMOS Compatible Input Levels
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 4.5 to 5.5 V
- Low Input Current: 1.0 μA; 0.1 μA @ 25°C
- Outputs Source/Sink 24 mA



PIN ASSIGNMENT

P ₁	1•	16]	v _{cc}
Q_1	2	15		P ₀
Q_0	3	14	_	MR
CPD	4	13]	$\overline{\mathrm{TC}}_{\mathrm{D}}$
ср _и [5	12]	$\overline{\mathrm{TC}}_{\mathrm{U}}$
Q_2	6	11]	PL
Q ₃ [7	10]	P ₂
GND	8	9]	P ₃

LOGIC DIAGRAM



 $\begin{array}{l} PIN \ 16 = V_{CC} \\ PIN \ 8 = GND \end{array}$



MAXIMUM RATINGS^{*}

Symbol	Parameter	Value	Unit
V _{CC}	DC Supply Voltage (Referenced to GND)	-0.5 to +7.0	V
V _{IN}	DC Input Voltage (Referenced to GND)	-0.5 to V_{CC} +0.5	V
V _{OUT}	DC Output Voltage (Referenced to GND)	-0.5 to V_{CC} +0.5	V
I _{IN}	DC Input Current, per Pin	±20	mA
I _{OUT}	DC Output Sink/Source Current, per Pin	±50	mA
I _{CC}	DC Supply Current, V_{CC} and GND Pins	±50	mA
P _D	Power Dissipation in Still Air, Plastic DIP+ SOIC Package+	750 500	mW
Tstg	Storage Temperature	-65 to +150	°C
T _L	Lead Temperature, 1 mm from Case for 10 Seconds (Plastic DIP or SOIC Package)	260	°C

*Maximum Ratings are those values beyond which damage to the device may occur.

Functional operation should be restricted to the Recommended Operating Conditions.

+Derating - Plastic DIP: - 10 mW/°C from 65° to 125°C

SOIC Package: : - 7 mW/°C from 65° to 125°C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V _{CC}	DC Supply Voltage (Referenced to GND)	4.5	5.5	V
V_{IN}, V_{OUT}	DC Input Voltage, Output Voltage (Referenced to GND)	0	V _{CC}	V
TJ	Junction Temperature (PDIP)		140	°C
T _A	Operating Temperature, All Package Types	-40	+85	°C
I _{OH}	Output Current - High		-24	mA
I _{OL}	Output Current - Low		24	mA
t _r , t _f	Input Rise and Fall Time * $V_{CC} = 4.5 \text{ V}$ (except Schmitt Inputs) $V_{CC} = 5.5 \text{ V}$	0 0	10 8.0	ns/V

 $^{\ast}V_{IN}~$ from 0.8 V to 2.0 V

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{IN} and V_{OUT} should be constrained to the range $GND \leq (V_{IN} \text{ or } V_{OUT}) \leq V_{CC}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

			V_{CC}	Guarant	eed Limits	
Symbol	Parameter	Test Conditions	v	25 °C	-40°C to 85°C	Unit
V_{IH}	Minimum High- Level Input Voltage	V_{OUT} =0.1 V or V_{CC} -0.1 V	4.5 5.5	2.0 2.0	2.0 2.0	V
V_{IL}	Maximum Low - Level Input Voltage	V_{OUT} =0.1 V or V_{CC} -0.1 V	4.5 5.5	0.8 0.8	0.8 0.8	V
V _{OH}	Minimum High- Level Output Voltage	$I_{OUT} \leq -50 \ \mu A$	4.5 5.5	4.4 5.4	4.4 5.4	V
		$V_{IN}=V_{IH}$ or V_{IL} $I_{OH}=-24$ mA $I_{OH}=-24$ mA	4.5 5.5	3.86 4.86	3.76 4.76	
V _{OL}	Maximum Low- Level Output Voltage	$I_{OUT} \leq 50 \ \mu A$	4.5 5.5	0.1 0.1	0.1 0.1	V
		$V_{IN}=V_{IH}$ $I_{OL}=24 \text{ mA}$ $I_{OL}=24 \text{ mA}$	4.5 5.5	0.36 0.36	0.44 0.44	
\mathbf{I}_{IN}	Maximum Input Leakage Current	V _{IN} =V _{CC} or GND	5.5	±0.1	±1.0	μA
I _{OLD}	+Minimum Dynamic Output Current	V _{OLD} =1.65 V Max	5.5		75	mA
I _{OHD}	+Minimum Dynamic Output Current	V _{OHD} =3.85 V Min	5.5		-75	mA
I _{CC}	Maximum Quiescent Supply Current (per Package)	V _{IN} =V _{CC} or GND	5.5	8.0	80	μΑ

DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

* All outputs loaded; thresholds on input associated with output under test.

+Maximum test duration 2.0 ms, one output loaded at a time.

FUNCTION TABLE

	Iı	Mode		
MR	PL	CP _U	CP _D	
Н	Х	X	X	Reset(Asyn.)
L	L	Х	Х	Preset(Asyn.)
L	Н	/	Н	No Count
L	Н		Н	Count Up
L	Н	Н		Count Down
L	Н	Н	$\left \right $	No Count

X = don't care

The KK74ACT193 is an UP/DOWN MODULO-16 Binary Counter. Logic equations For Terminal Count:

$$\frac{TC_U}{TC_D} = Q_0 \bullet Q_1 \bullet Q_2 \bullet Q_3 \bullet CP_U$$
$$TC_D = Q_0 \bullet Q_1 \bullet Q_2 \bullet Q_3 \bullet CP_D$$

			Guaranteed Limits			
Symbol	Parameter	25 °C		-40°C to 85°C		Unit
		Min	Max	Min	Max	
\mathbf{f}_{max}	Maximum Clock Frequency (Figure 1)	100		80		MHz
t _{PLH}	Propagation Delay, CP_U or CP_D to TC_U or TC_D (Figure 2)		15		16.5	ns
t _{PHL}	Propagation Delay, CP_U or CP_D to TC_U or TC_D (Figure 2)		14		15.5	ns
t _{PLH}	Propagation Delay, CP_U or CP_D to Q_n (Figure 1)		12		13.5	ns
t _{PHL}	Propagation Delay, CP_U or CP_D to Q_n (Figure 1)		12		13.5	ns
t _{PLH}	Propagation Delay, P_n to Q_n (Figure 3)		12		13.5	ns
t _{PHL}	Propagation Delay, P_n to Q_n (Figure 3)		12		13.5	ns
t _{PLH}	Propagation Delay, PL to Q_n (Figure 4)		12		13.5	ns
t _{PHL}	Propagation Delay, PL to Q_n (Figure 4)		15		16.5	ns
t _{PHL}	Propagation Delay, MR to Q_n (Figure 5)		15		16.5	ns
t _{PLH}	Propagation Delay, MR to TC_U (Figure 6)		14		15.5	ns
t _{PHL}	Propagation Delay, MR to TC_D (Figure 6)		14		15.5	ns
t _{PLH}	Propagation Delay, PL to TC_U or TC_D (Figure 6)		15		16.5	ns
t _{PHL}	Propagation Delay, PL to TC_U or TC_D (Figure 6)		11		12.5	ns
t _{PLH}	Propagation Delay, $P_n to TC_U to TC_D$ (Figure 6)		15		16.5	ns
t _{PHL}	Propagation Delay, $P_n to TC_U to TC_D$ (Figure 6)		15		16.5	ns
C _{IN}	Maximum Input Capacitance	4.	.5	4	.5	pF
		Туріс	al @25°	C,V _{CC} =	5.0 V	
C_{PD}	Power Dissipation Capacitance		4	5		pF

AC ELECTRICAL CHARACTERISTICS (V_{CC} =5.0 V ± 10%, C_L =50pF,Input t_r=t_f=3.0 ns)

		Typical @25°C,V _{CC} =5.0 V	
C _{PD}	Power Dissipation Capacitance	45	pF

3.0 V

GND

		Guarantee	ed Limits	
Symbol	Parameter	25 °C	-40°C to 85°C	Unit
t _{su}	Minimum Setup Time, P_n to PL (Figure 7)	8	9	ns
t _h	Minimum Hold Time, PL to P_n (Figure 7)	-1.0	-1.0	ns
t _w	Minimum Pulse Width, PL (Figure 4)	14	15	ns
t _w	Minimum Pulse Width, CP_U or CP_D (Figure 1)	10	11	ns
t _w	Minimum Pulse Width, MR (Figure 5)	12	14	ns
t _{rec}	Minimum Recovery Time, PL to CP_U or CP_D (Figure 5)	8	9	ns
t _{rec}	Minimum Recovery Time, MR to CP_U or CP_D (Figure 5)	14	16	ns

TIMING REQUIREMENTS (C_L=50pF, Input t_r=t_f=3.0 ns, V_{CC}=5.0 V \pm 10%)

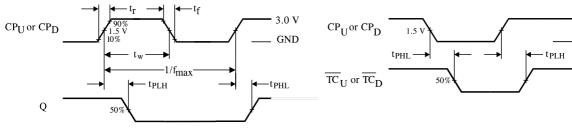
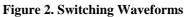
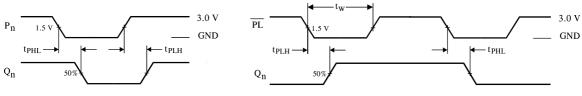
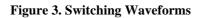
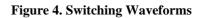


Figure 1. Switching Waveforms



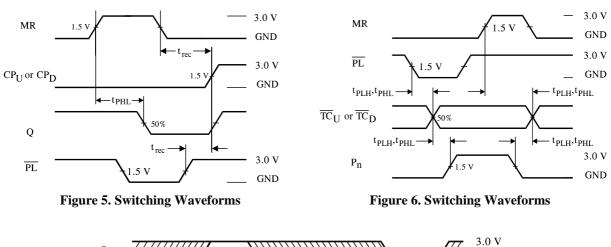












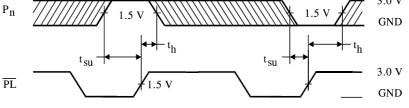
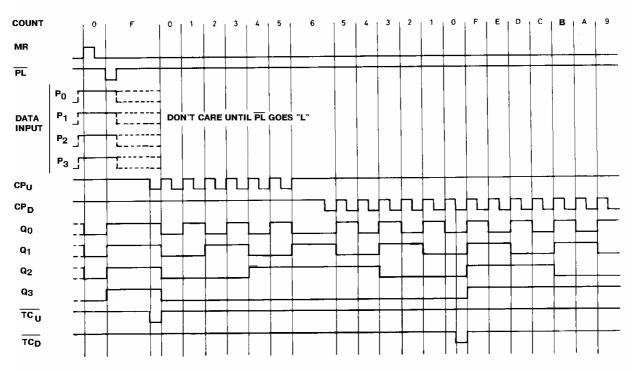


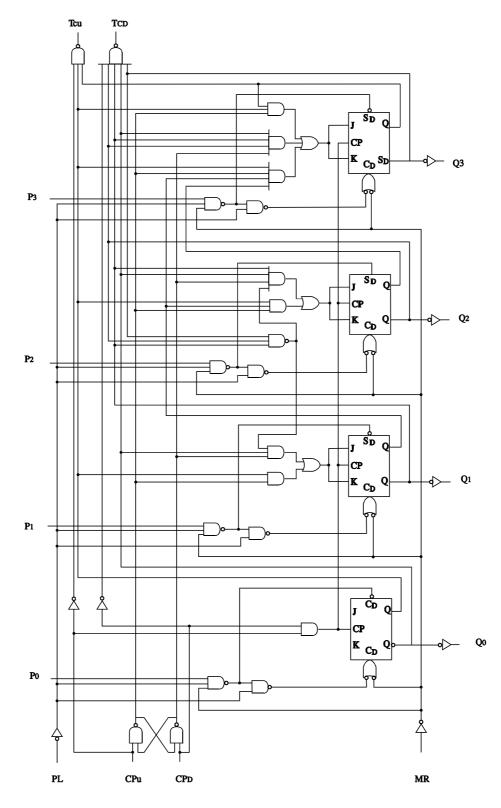
Figure 7. Switching Waveforms

TIMING DIAGRAM



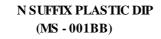


EXPANDED LOGIC DIAGRAM



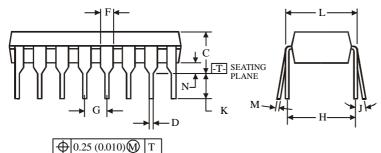








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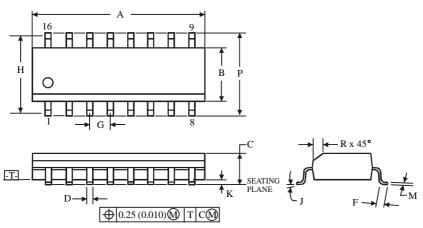
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 Dimensions "A", "B" do not include mold flash or protrusions. Maximum mold flash or protrusions 0.25 mm (0.010) per side.

	1			
	Dimension, mm			
Symbol	MIN	MAX		
Α	18.67	19.69		
В	6.1	7.11		
С		5.33		
D	0.36	0.56		
F	1.14	1.78		
G	2.	54		
Н	7.	62		
J	0°	10°		
K	2.92	3.81		
L	7.62	8.26		
М	0.2	0.36		
Ν	0.38			

D SUFFIX SOIC (MS - 012AC)



NOTES:

- 1. Dimensions A and B do not include mold flash or protrusion.
- 2. Maximum mold flash or protrusion 0.15 mm (0.006) per side for A; for B 0.25 mm (0.010) per side.



	Dimension, mm			
Symbol	MIN	MAX		
Α	9.8	10		
В	3.8	4		
С	1.35	1.75		
D	0.33	0.51		
F	0.4	1.27		
G	1.	27		
Н	5.	72		
J	0°	8°		
K	0.1	0.25		
М	0.19 0.25			
Р	5.8	6.2		
R	0.25	0.5		